HAMAMATSU

PHOTON IS OUR BUSINESS



Si PIN photodiodes

S5971 S5972

S5973 series

High-speed photodiodes (S5973 series: 1 GHz)

The S5971, S5972 and S5973 series are high-speed Si PIN photodiodes designed for visible to near infrared light detection. These photodiodes provide wideband characteristics at a low bias, making them suitable for optical communications and other high-speed photometry. The S5973 series includes a mini-lens type (S5973-01) that can be efficiently coupled to an optical fiber and a violet sensitivity enhanced type (S5973-02) ideal for violet laser detection.

- Features

→ High-speed response

S5971 : 100 MHz (VR=10 V) S5972 : 500 MHz (VR=10 V) S5973 series: 1 GHz (VR=3.3 V)

- → Low price
- High sensitivity

S5973-02: 0.3 A/W, QE=91 % (λ=410 nm)

High reliability

Applications

- Optical fiber communications
- High-speed photometry
- **Violet laser detection (S5973-02)**

Structure / Absolute maximum ratings

Type no.	Dimensional			Effective	Absolute maximum ratings					
	outline/ Window	Package	Photosensitive area size	photosensitive	Reverse voltage	Power dissipation		Storage temperature		
	material*1				VR Max.	P	Topr	Tstg		
		(mm)	(mm)	(mm²)	(V)	(mW)	(°C)	(°C)		
S5971			φ1.2	1.1		50	-40 to +100	-55 to +125		
S5972	(1)/K		φ0.8	0.5						
S5973		TO-18	φ0.4		20					
S5973-01	(2)/L			0.12						
S5973-02	(3)/K									

Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

Electrical and optical characteristics

Type no.	Spectral response range	Peak sensitivity wavelength λp	Photosensitivity S (A/W)			Short circuit current Isc	Dark current ID		Temp. coefficient of ID	Cutoff frequency fc	Ct	Noise equivalent power NEP V _R =10 V	
., pe				660	780	830	100 lx			TCID		f=1 MHz	λ=λp
			λр	nm	nm	nm		Тур.	Max.	1			
	(nm)	(nm)					(µA)	(nA)	(nA)	(times/°C)	(GHz)	(pF)	(W/Hz ^{1/2})
S5971	320 to 1060	900	0.64	0.44	0.55	0.6	1.0	0.07*3	1* ³	1.15	0.1*3	3*3	7.4×10^{-15}
S5972		800	0.57			0.55	0.42	0.01*3	0.5*3		0.5*3		3.1 × 10 ⁻¹⁵
S5973	320 to 1000	760 760	0.52		0.51	0.47	0.09		*4 0.1*4		1*4	1.6*4	1.1 × 10 ⁻¹⁵ * ⁴
S5973-01							0.42	0.001*4					
S5973-02			0.4	0.3*2	0.42	0.37	0.07						1.9 × 10 ⁻¹⁵ *2 *4

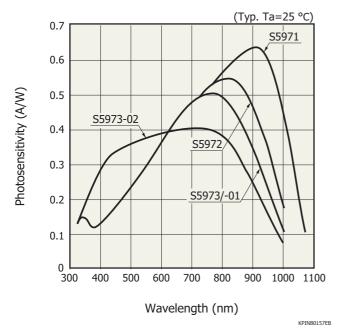
^{*1:} Window material K: borosilicate glass, L: lens type borosilicate glass

^{*2:} λ=410 nm

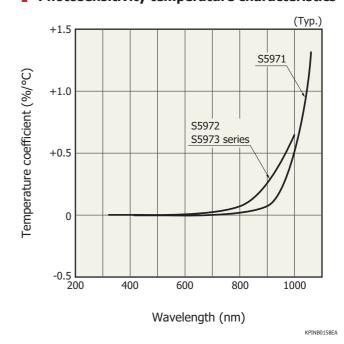
^{*3:} V_R=10 V

^{*4:} VR=3.3 V

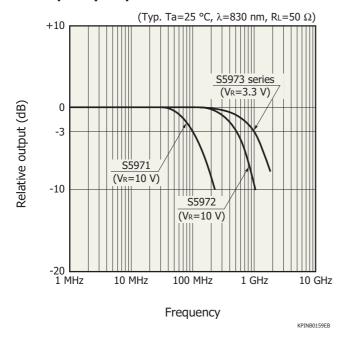
Spectral response



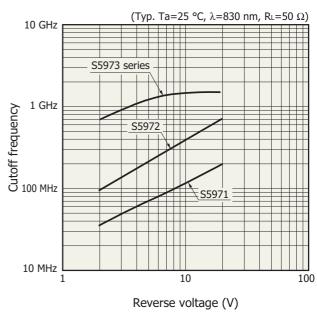
▶ Photosensitivity temperature characteristics



Frequency response

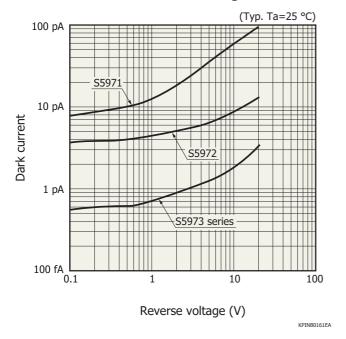


- Cutoff frequency vs. reverse voltage

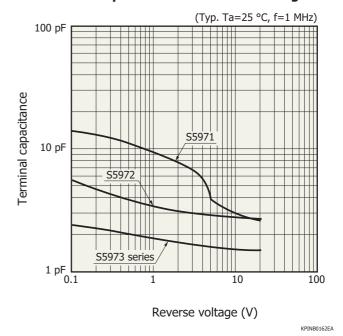


KPINB0160EB

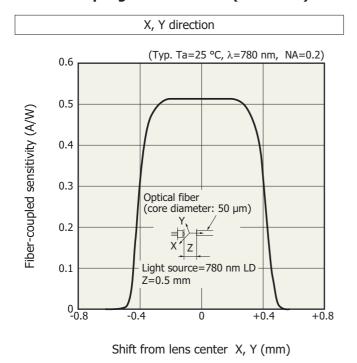
Dark current vs. reverse voltage

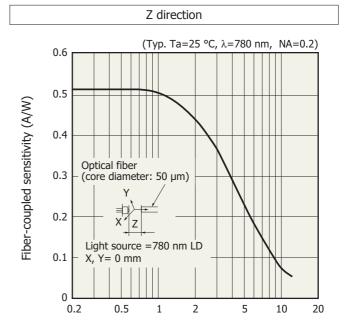


Terminal capacitance vs. reverse voltage



Fiber coupling characteristics (\$5973-01)





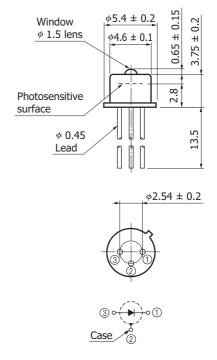
Distance between lens and fiber end Z (mm)

Dimensional outlines (unit: mm)

(1) S5971, S5972, S5973

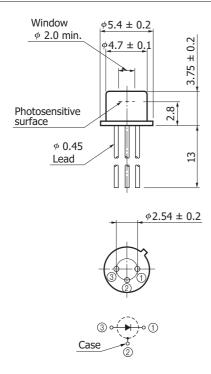
Window ϕ 3.0 \pm 0.2 ϕ 4.7 \pm 0.1 ϕ 9. Photosensitive surface ϕ 0.45 Lead ϕ 2.54 \pm 0.2

(2) S5973-01



KPINA0023EA

(3) S5973-02



KPINA0061EB

Si PIN photodiodes

S5971, S5972, S5973 series

Related information

www.hamamatsu.com/sp/ssd/doc_en.html

- Precautions
- Disclaimer
- Metal, ceramic, plastic package products
- Technical information
- · Si photodiode / Application circuit example

Information described in this material is current as of November, 2015.

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HAMAMATSU PHOTONICS K.K., Solid State Division

HAMAMATSU PHOTONICS K.K., Solid State Division

1126-1 Ichino-cho, Higashi-ku, Hamamatsu City, 435-8558 Japan, Telephone: (81) 53-434-3311, Fax: (81) 53-434-5184

U.S.A.: Hamamatsu Corporation: 360 Foothill Road, Bridgewater, N.J. 08807, U.S.A., Telephone: (1) 908-231-0960, Fax: (1) 908-231-1218

Germany: Hamamatsu Photonics Deutschland GmbH: Arzbergerstr. 10, D-82211 Herrsching am Ammersee, Germany, Telephone: (49) 8152-375-0, Fax: (49) 8152-265-8

France: Hamamatsu Photonics France S.A.R.L.: 19, Rue du Saule Trapu, Parc du Moulin de Massy, 91882 Massy Cedex, France, Telephone: 33-(1) 69 53 71 00, Fax: 33-(1) 69 53 71 10

United Kingdom: Hamamatsu Photonics UK Limited: 2 Howard Court, 10 Tewin Road, Welwyn Garden City, Hertfordshire AL7 1BW, United Kingdom, Telephone: (44) 1707-294888, Fax: (44) 1707-325777

North Europe: Hamamatsu Photonics Norden AB: Torshamnsgatan 35 16440 Kista, Sweden, Telephone: (46) 8-509-031-00, Fax: (46) 8-509-031-01

Italy: Hamamatsu Photonics (China) Co., Ltd.: B1201, Jiaming Center, No.27 Dongsanhuan Beilu, Chaoyang District, Beijing 100020, China, Telephone: (86) 10-6586-6006, Fax: (86) 10-6586-2866